Erratum to: Field-effect at electrical contacts to two-dimensional materials

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The article *Field-effect at electrical contacts to two-dimensional materials*, written by Yao Guo et al., was erroneously originally published electronically on the publisher's internet portal (currently SpringerLink) on 28 July 2021 with Ref. [27] and Table of contents.

Instead of

[27] McClellan, C. J.; Yalon, E.; Smithe, K. K. H.; Suryavanshi, S. V.; Pop, E. Effective n-type doping of monolayer MoS₂ by AlO_x. In *Proceedings of the 2017 75th Annual Device Research Conference*, South Bend, 2017, pp 1–2.

It should read

[27] Connor J. McClellan, Eilam Yalon, Kirby K. H. Smithe, Saurabh V. Suryavanshi, and Eric Pop*. High current density in monolayer MoS₂ doped by AlO_x. *ACS Nano* 2021, 15, 1587–1596.

Instead of

It should read

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